# **BGF110**

SD Card Interface ESD Protection

**Small Signal Discretes** 



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# **BGF110**

**Revision History: 2007-07-04, V2.2** 

Previous Version: 2006-10-	1	7	
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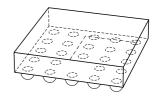
FIEVIOU	rievious version. 2006-10-17					
Page	Subjects (major changes since last revision)					
4	EMI and cross talk feature added					
4	Contact discharge added					



# **SD Card Interface ESD Protection**

#### **Feature**

- · ESD protection for SD Card interface
- Integrated ESD protection up to 15 kV contact discharge
- · Very good EMI filtering with very low cross talk
- Green wafer level package with SnAgSu solder balls
- 400 μm solder ball pitch



WLP-24-2



## **Description**

The BGF110 is an ESD protection for the SD Card interface using a green wafer level package. External pins are protected up to 15 kV contact discharge according to IEC61000-4-2. A RF filter functionality provides very good RF and EMI suppression on the digital lines with very low cross talk. Sensitivity of the line capacitance on the bias voltage is very low. The wafer level package has a 400  $\mu$ m solder ball pitch and 250  $\mu$ m ball diameter (before ball attach).

Type Package		Marking	Chip		
BGF110	WLP-24-2	BGF110	N0720		

#### Table 1 Maximum Ratings

Parameter	Symbol	Values			Unit	Note /
		Min.	Тур.	Max.		Test Condition
Voltage at all pins to GND	$V_{P}$	-14		14	V	
Operating temperature range	$T_{OP}$	-40		+85	°C	
Storage temperature range	$T_{STG}$	-65		+150	°C	
Maximum current at all pins	$I_{max}$			113 <sup>1)</sup>	mA	
Electrostatic discharge according to IEC61000-4-2 (co	ontact disc	charge)				
Ext. IOs: A4, A5, B4, B5, C4, C5, D4, D5, E4, E5	$V_{E}$	-15		15	kV	
Int. IOs: A1, A2, B1, B2, C1, C2, C3, D1, D2, E1, E2	$V_1$	-2		2	kV	

<sup>1)</sup> Can be applied for 24 hours if thermal power dissipation into PCB is considered properly



Table 2 Electrical Characteristics<sup>1)</sup>

Parameter	Symbol		Values			Note /	
		Min.	Тур.	Max.		<b>Test Condition</b>	
Series Resistors							
$R_1, R_2, R_3, R_4, R_5, R_6, R_7, R_8, R_9$	$R_{19}$	32	40	48	Ω		
$R_{11}, R_{12}, R_{13}, R_{14}$	$R_{1114}$	35	50	65	$k\Omega$		
$R_{15}$	$R_{15}$	10.5	15	19.5	$k\Omega$		
$R_{21}$	$R_{21}$	329	470	611	$k\Omega$		
Reverse current of ESD protection diodes	$I_{R}$		0.1	120	nA	V <sub>R</sub> = 3 V	
			0.1	120	μΑ	$V_{\rm R}$ = 14 V	
Line capacitance	$C_{T}$		13.5	20	pF	V <sub>R</sub> = 0 V	
Capacitance of each line to GND <sup>2)</sup>			11.5			$V_{\rm R} = 5 \text{ V}$	

<sup>1)</sup> at  $T_{A} = 25 \,^{\circ}\text{C}$ 

<sup>2)</sup> Without line coupling by resistors  $R_{11}$  -  $R_{21}$ 

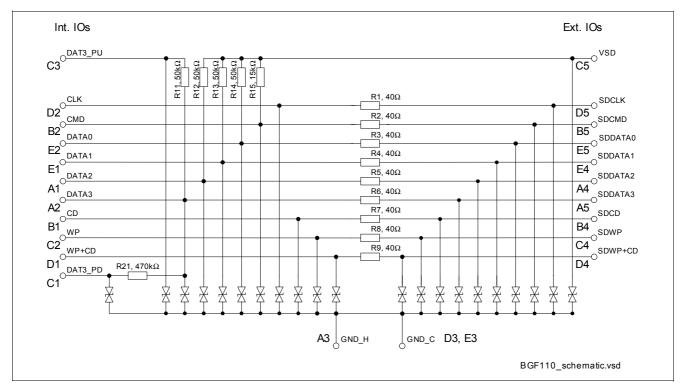


Figure 1 Schematic



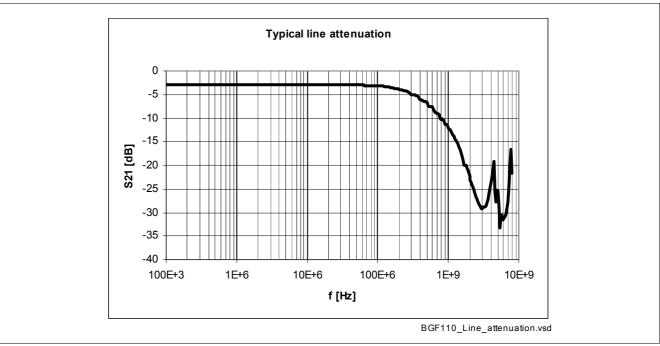


Figure 2 Line attenuation  $Z_{S} = Z_{L} = 50 \Omega$ 

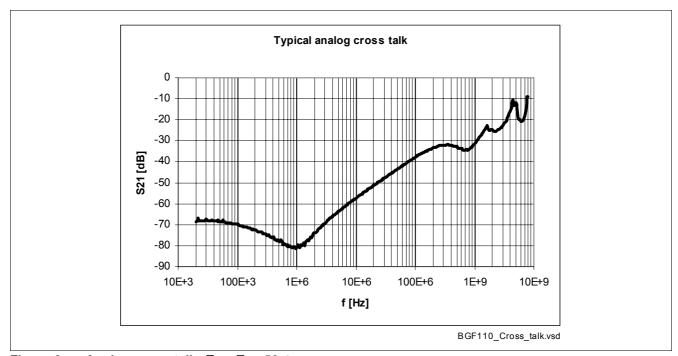


Figure 3 Analog cross talk,  $Z_S = Z_L = 50 \Omega$ 



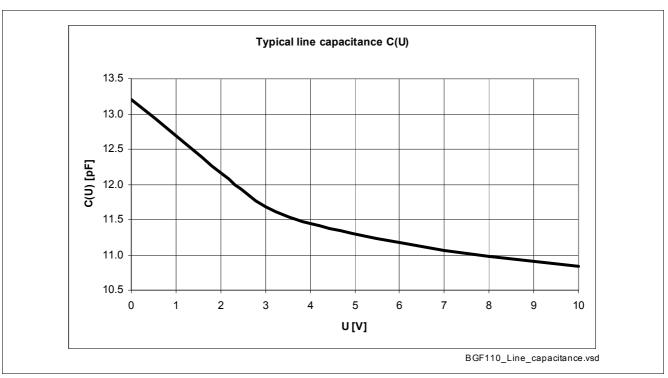


Figure 4 Line capacitance versus bias voltage

## **Package Outline**

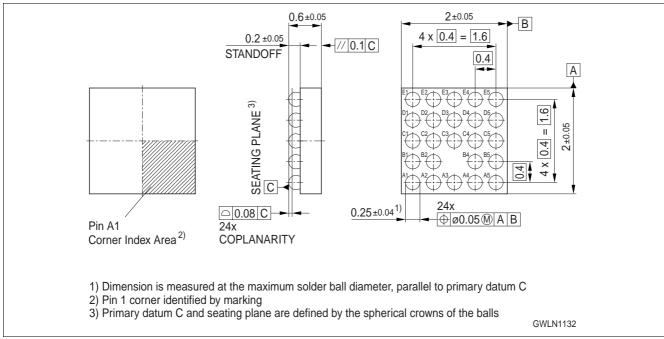


Figure 5 Package WLP-24-2



# Tape and reel specification

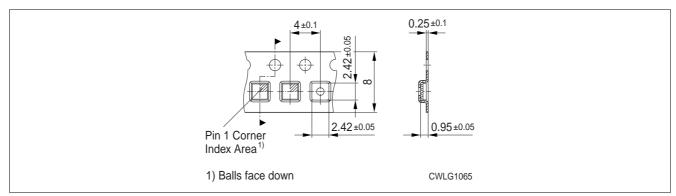


Figure 6 Tape for WLP-24-2